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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO
10/625,546	07/24/2003	Yutaka Hirose	YMOR:294	8197
6160	7590 01/04/2005		EXAMINER	
PARKHURST & WENDEL, L.L.P. 1421 PRINCE STREET			PAREKH, NITIN	
SUITE 210	SIREEI		ART UNIT	PAPER NUMBER
ALEXANDR	ALEXANDRIA, VA 22314-2805 2811			

DATE MAILED: 01/04/2005

Please find below and/or attached an Office communication concerning this application or proceeding.

	10/625,546	HIROSE ET AL.	8			
Office Action Summary	Exa <i>M</i> n er	A/t Unit				
	Nitin Parekh	2811				
The MAILING DATE of this communication app		1				
Period for Reply			_			
A SHORTENED STATUTORY PERIOD FOR REPLY THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply - If NO period for reply is specified above, the maximum statutory period w - Failure to reply within the set or extended period for reply will, by statute, Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	36(a). In no event, however, may a reply be within the statutory minimum of thirty (30) drill apply and will expire SIX (6) MONTHS frocause the application to become ABANDON	timely filed lays will be considered timely, om the mailing date of this commu NED (35 U.S.C. § 133).	inication.			
Status						
1) Responsive to communication(s) filed on 01 No	ovember 2004.					
2a) ☐ This action is FINAL. 2b) ☐ This	action is non-final.					
3) Since this application is in condition for allowan	nce except for formal matters, p	rosecution as to the me	erits is			
closed in accordance with the practice under E	x parte Quayle, 1935 C.D. 11,	453 O.G. 213.				
Disposition of Claims						
4)⊠ Claim(s) <u>1-4</u> is/are pending in the application.						
4a) Of the above claim(s) 4 is/are withdrawn fro	m consideration.		٠			
5) Claim(s) is/are allowed.		,				
6)⊠ Claim(s) <u>1-3</u> is/are rejected.						
7) Claim(s) is/are objected to.						
8) Claim(s) are subject to restriction and/or	r election requirement.					
Application Papers						
9) The specification is objected to by the Examiner	r.					
10) ☐ The drawing(s) filed on <u>24 July 2003</u> is/are: a) [by the Examiner.				
Applicant may not request that any objection to the o		•				
Replacement drawing sheet(s) including the correcti	J.,	` '	.121(d).			
11) The oath or declaration is objected to by the Ex	aminer. Note the attached Offic	e Action or form PTO-1	52 .			
Priority under 35 U.S.C. § 119						
12)⊠ Acknowledgment is made of a claim for foreign	priority under 35 H.S.C. & 119/	a)-(d) or (f)				
a) ⊠ All b) ☐ Some * c) ☐ None of:	priority under 55 0.0.0. § 119(a)-(u) or (i).				
1.⊠ Certified copies of the priority documents	s have been received					
2. Certified copies of the priority documents		ation No.				
3. Copies of the certified copies of the priori	*		ne e			
application from the International Bureau	* .	vou in tino reational ota	90			
* See the attached detailed Office action for a list of	, ,,	ved.				
	·					
Attachment(s)						
1) Notice of References Cited (PTO-892)	4) Interview Summa					
2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08)	Paper No(s)/Mail 5) Notice of Informal	Date Patent Application (PTO-152	n			
3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date	6) Other:	, atom ripphoduoit (FTO-102	•1			
U.S. Patent and Trademark Office PTOL-326 (Rev. 1-04) Office Act	tion Summary	Part of Paper No./Ma	il Date 6			

Application/Control Number: 10/625,546

Art Unit: 2811

DETAILED ACTION

Claim Rejections - 35 USC § 102

1. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless –

(e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

2. Claims 1-3 are rejected under 35 U.S.C. 102 (e) as being anticipated by Herner et al. (US Pat. 2003/0030147).

Regarding claims 1-3, Herner et al. disclose a contact/an ohmic contact formation method comprising:

- forming a composite film comprising silicon (Si) and titanium (Ti) on a surface layer of a semiconductor region (see 28 and 30 respectively on the region 12 in Fig. 3; sections 0021-0023) of a semiconductor material including a Group III nitride semiconductor (see section 0039)
- the Si and Ti films being formed in the order of depositing Si followed by Ti (sections 0022, 0023 and 0028), and

Application/Control Number: 10/625,546 Page 3

Art Unit: 2811

- heat treating/annealing the films and the semiconductor layer at a temperature of

about 800 deg. C (section 0025)

(Fig. 2-5; sections 0022-0039; pp. 1-4).

Response to Arguments

3. Applicant's arguments filed on 11-01-04 have been fully considered but they are

not persuasive.

A. Applicant contends that Herner et al. disclose forming TiSi layer by heat

treatment, but do not disclose such formation by diffusing Si as dopant in the

semiconductor layer as recited in the claim 1.

However, such limitations are not recited in the amended claim 1.

Conclusion

4. THIS ACTION IS MADE FINAL. Applicant is reminded of the extension of time

policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE

MONTHS from the mailing date of this action. In the event a first reply is filed within

TWO MONTHS of the mailing date of this final action and the advisory action is not

mailed until after the end of the THREE-MONTH shortened statutory period, then the

shortened statutory period will expire on the date the advisory action is mailed, and any

extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of

Art Unit: 2811

the advisory action. In no event, however, will the statutory period for reply expire later

than SIX MONTHS from the mailing date of this final action.

Any inquiry concerning this communication or earlier communications from the

examiner should be directed to Nitin Parekh whose telephone number is 571-272-1663.

The examiner can normally be reached on 09:00AM-05:30PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor, Eddie Lee can be reached on 571-272-1732. The fax phone number for the

organization where this application or proceeding is assigned is 703-872-9318.

Any inquiry of a general nature or relating to the status of this application or

proceeding should be directed to the receptionist whose telephone number is 703-308-

0956.

Nitin Parekh

Nati Pareles

PRIMARY EXAMINER

TECHNOLOGY CENTER 2800

NP

12-29-04